

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	9.8491	N/A	7.7490
RT2	42.6563	N/A	26.4232
RT3	41.8008	N/A	10.7696
RT4	71.6938	N/A	4.9549
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	143.1562u	N/A	211.0863m
CT2	15.7258m	N/A	15.8714m
CT3	3.3587m	N/A	8.1167m
CT4	991.3470m	N/A	654.2942u

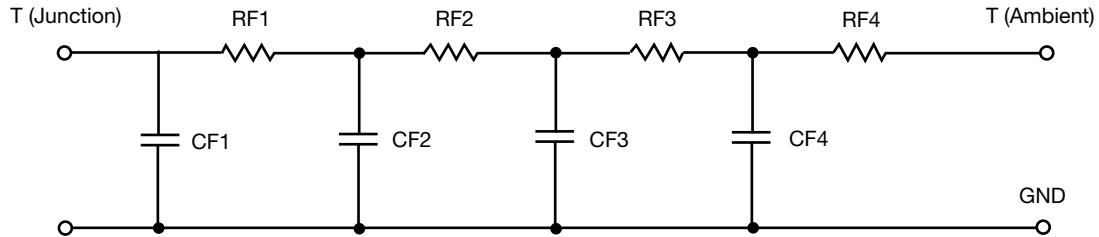
#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*



**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	15.7856	N/A	13.3748
RF2	53.2710	N/A	21.0572
RF3	27.8023	N/A	10.9937
RF4	69.1411	N/A	4.4976
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	513.7126u	N/A	1.4669m
CF2	2.5363m	N/A	8.3839m
CF3	18.6939m	N/A	17.0885m
CF4	1.0435	N/A	279.9907m

**Note**

N/A indicates not applicable

